

Form 1449 (Modified)

Information Disclosure Statement By Applicant Atty Docket No. NOVLP090/NVLS-2888 Application No.: 10/733,858

Applicant: Zhu et al.

Znu et al. Filing Date

Group 2891

(Use Several Sheets if Necessary)

December 10, 2003

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Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.